

**IN THE CLAIMS:**

This listing of claims will replace all prior versions, and listings, of claims in the application:

1-11 (Canceled).

12 (Currently Amended). An organic electroluminescence display device comprising:

a resin substrate; and

an insulating film comprising a nitride in contact with the resin substrate; and

an electroluminescent element formed over the insulating film, said electroluminescent element having a light emitting layer comprising an organic material.

13 (Previously Presented). The organic electroluminescence display device according to claim 12 wherein said resin substrate comprises polyethylene terephthalate.

14 (Previously Presented). The organic electroluminescence display device according to claim 12 wherein said insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

15 (Currently Amended). An organic electroluminescence display device comprising:

a resin substrate; and

an underlying insulating film formed in contact with the resin substrate, and

an electroluminescent element formed over the insulating film, said electroluminescent element having a light emitting layer comprising an organic material.

wherein the underlying insulating film comprises a first insulating film comprising a nitride and a second insulating film comprising silicon oxide.

16 (Previously Presented). The organic electroluminescence display device according to claim 15 wherein said resin substrate comprises polyethylene terephthalate.

17 (Previously Presented). The organic electroluminescence display device according to claim 15 wherein said first insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

18 (Currently Amended). An organic electroluminescence display device comprising:

- a resin substrate;
- an insulating film comprising a nitride on the resin substrate; and
- a thin film transistor formed over the insulating film; and
- an electroluminescent element electrically connected to said thin film transistor, said electroluminescent element having a light emitting layer comprising an organic material.

19 (Previously Presented). The organic electroluminescence display device according to claim 18 wherein said resin substrate comprises polyethylene terephthalate.

20 (Previously Presented). The organic electroluminescence display device according to claim 18 wherein said insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

21. (Currently Amended). An organic electroluminescence display device comprising:

- a resin substrate;
- an underlying insulating film formed on the resin substrate; and
- a thin film transistor formed over the underlying insulating film, and  
an electroluminescent element electrically connected to said thin film transistor, said  
electroluminescent element having a light emitting layer comprising an organic material

wherein the underlying insulating film comprises a first insulating film comprising a nitride and a second insulating film comprising silicon oxide.

22 (Previously Presented). The organic electroluminescence display device according to claim 22 wherein said resin substrate comprises polyethylene terephthalate.

23 (Previously Presented). The organic electroluminescence display device according to claim 22 wherein said first insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

24 (Currently Amended). An organic electroluminescence display device comprising:

- a resin substrate;
- an insulating film comprising a nitride in contact with the resin substrate; and
- a channel region of a thin film transistor, wherein the channel region comprises amorphous silicon and is formed over the insulating film; and

an electroluminescent element formed over the insulating film and electrically connected to said thin film transistor, said electroluminescent element having a light emitting layer comprising an organic material.

25 (Previously Presented). The organic electroluminescence display device according to claim 24 wherein said resin substrate comprises polyethylene terephthalate.

26 (Previously Presented). The organic electroluminescence display device according to claim 24 wherein said insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

27 (Currently Amended). An organic electroluminescence display device comprising:

- a resin substrate;
- an underlying insulating film formed on the resin substrate; and
- a channel region of a thin film transistor formed over the underlying insulating film, said channel region comprising amorphous silicon, and  
an electroluminescent element electrically connected to said thin film transistor, said electroluminescent element having a light emitting layer comprising an organic material,

wherein the underlying insulating film comprises a first insulating film comprising a nitride and a second insulating film comprising silicon oxide.

28 (Previously Presented). The organic electroluminescence display device according to claim 27 wherein said resin substrate comprises polyethylene terephthalate.

29 (Previously Presented). The organic electroluminescence display device according to claim 27 wherein said first insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

30 (Currently Amended). An organic electroluminescence display device comprising:

- a resin substrate;
- an insulating film comprising a nitride in contact with the resin substrate; and
- a channel region of a thin film transistor, wherein the channel region comprises crystalline silicon and is formed over the insulating film, and  
an electroluminescent element formed over the insulating film and electrically connected to said thin film transistor, said electroluminescent element having a light emitting layer comprising an organic material

31 (Previously Presented). The organic electroluminescence display device according to claim 30 wherein said resin substrate comprises polyethylene terephthalate.

32 (Previously Presented). The organic electroluminescence display device according to claim 30 wherein said insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

33 (Currently Amended). An organic electroluminescence display device comprising:

- a resin substrate;
- an underlying insulating film formed on the resin substrate; and
- a channel region of a thin film transistor formed over the underlying insulating film,

said channel region comprising crystalline silicon, and

an electroluminescent element formed over the insulating film and electrically connected to said thin film transistor, said electroluminescent element having a light emitting layer comprising an organic material

wherein the underlying insulating film comprises a first insulating film comprising a nitride and a second insulating film comprising silicon oxide.

34 (Previously Presented). The organic electroluminescence display device according to claim 33 wherein said resin substrate comprises polyethylene terephthalate.

35 (Previously Presented). The organic electroluminescence display device according to claim 33 wherein said first insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

36 (Currently Amended). An organic electroluminescence display device comprising:

- a resin substrate; and
- an insulating film comprising an oxy-nitride in contact with the resin substrate; and

an electroluminescent element formed over the insulating film, said electroluminescent element having a light emitting layer comprising an organic material.

37 (Previously Presented). The organic electroluminescence display device according to claim 36 wherein said resin substrate comprises polyethylene terephthalate.

38 (Currently Amended). An organic electroluminescence display device comprising:

- a resin substrate;
- an insulating film comprising an oxy-nitride on the resin substrate; and
- a thin film transistor formed over the insulating film; and
- an electroluminescent element formed over the insulating film and electrically connected to said thin film transistor, said electroluminescent element having a light emitting layer comprising an organic material.

39 (Previously Presented). The organic electroluminescence display device according to claim 38 wherein said resin substrate comprises polyethylene terephthalate.

40 (Currently Amended). An organic electroluminescence display device comprising:

- a resin substrate;
- an insulating film comprising an oxy-nitride on the resin substrate; and
- a channel region of a thin film transistor, wherein the channel region comprises amorphous silicon and is formed over the insulating film; and

an electroluminescent element formed over the insulating film, said electroluminescent element having a light emitting layer comprising an organic material.

41 (Previously Presented). The organic electroluminescence display device according to claim 40 wherein said resin substrate comprises polyethylene terephthalate.

42 (Currently Amended). An organic electroluminescence display device comprising:

- a resin substrate;
- an insulating film comprising an oxy-nitride on the resin substrate; and
- a channel region of a thin film transistor, wherein the channel region comprises crystalline silicon and is formed over the insulating film; and

an electroluminescent element formed over the insulating film, said electroluminescent element having a light emitting layer comprising an organic material.

43 (Previously Presented). The organic electroluminescence display device according to claim 42 wherein said resin substrate comprises polyethylene terephthalate.